

Silicon PNP transistor epitaxial type 6A958

[Applications]

High voltage switching and amplifier

[Feature]

High voltage VCEO= -400V

Low collector saturation voltage VCE(sat)= -0.75V (Max.) at IC= -50mA, IB= -5mA

Small collector output capacitance Cob= 3.5pF (Typ.) at VCB= -20V

NPN complementary pair with CP958

[Absolute maximum ratings (Ta=25C)]

| Characteristic | Symbol | Maximum ratings | Unit |
|---------------------------|--------|-----------------|------|
| Collector-base voltage | VCBO | -400 | V |
| Collector-emitter voltage | VCEO | -400 | V |
| Emitter-base voltage | VEBO | -6 | V |
| Collector current | IC | -300 | mA |
| Junction temperature | Tj | 150 | C |
| Storage temperature | Tstg | -55 to 150 | C |

[Electrical characteristics (Ta=25C)]

| Characteristic | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--|------------|------|------|-------|------|-----------------------------|
| Collector-base breakdown voltage | BVCBO | -400 | - | - | V | IC= -100uA |
| Collector-emitter breakdown voltage | BVCEO | -400 | - | - | V | IC= -1mA |
| Collector-emitter breakdown voltage | BVCES | -400 | - | - | V | IC= -100uA |
| Emitter-base breakdown voltage | BVEBO | -6 | - | - | V | IE= -10uA |
| Collector cut-off current | ICBO | - | - | -0.1 | uA | VCB= -400V |
| Collector cut-off current | ICES | - | - | -1 | uA | VCE= -400V |
| Emitter cut-off current | IEBO | - | - | -0.1 | uA | VEB= -4V |
| DC current gain 1 | hFE 1 | 40 | - | - | - | VCE= -10V, IC= -1mA |
| DC current gain 2 | hFE 2 | 80 | - | 300 | - | VCE= -10V, IC= -10mA |
| DC current gain 3 | hFE 3 | 45 | - | - | - | VCE= -10V, IC= -50mA |
| DC current gain 4 | hFE 4 | 40 | - | - | - | VCE= -10V, IC= -100mA |
| Collector-emitter saturation voltage 1 | VCE(sat) 1 | - | - | -0.5 | V | IC= -10mA, IB= -1mA |
| Collector-emitter saturation voltage 2 | VCE(sat) 2 | - | - | -0.75 | V | IC= -50mA, IB= -5mA |
| Base-emitter saturation voltage | VBE(sat) | - | - | -0.75 | V | IC= -10mA, IB= -1mA |
| Transition frequency | fT | 50 | - | - | MHz | VCE= -10V, IE= 10mA |
| Collector output capacitance | Cob | - | 3.5 | - | pF | VCB= -20V, f = 1MHz, IE= 0A |

Notice 1) These are measured data of transistors assembled by PHENITEC SEMICONDUCTOR Corp. and are for reference only.

Notice 2) The contents described herein are subject to change without notice.

